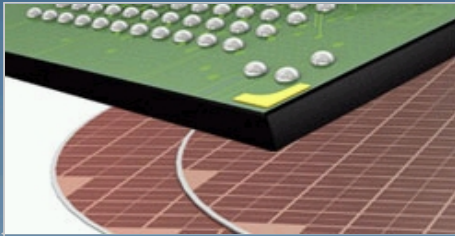


Advanced Search ▶

128Gb Mass Storage: MT29F128G08AUCBBH3-12



Micron NAND Flash uses an industry -proven floating gate cell and a standard interface to enable pin and function drop -in compatibility and easy integration into most existing designs.

Illustration Only. See data sheet for product specifications.

Data Sheets

16Gb, 32Gb, 64Gb, and 128Gb Asynchronous/Synchronous NAND (NDA)
3/2010
3MB

Certifications

RoHS Certificate of Compliance
China RoHS Certificate

Specifications

Density: 128Gb
Part Status: Production
RoHS: Yes
Bus Width: x8
Voltage: 3.3V
Package: LBGA
Pin Count: 100-ball
MT/s: 166 MT/s
I/O: Separate
Bits/Cell: SLC
Op Temp: 0C to +70C

- Order
- Tech Notes
- Documentation
- Sim Models

MT29F128G08AUCBBH312:B

Production orders are being taken, parts are shipping.

Contact a Sales Representative

Distributor Stock
Nu Horizons Electronics(50+)

Additional Info
ONFI 2.1

Orderable Part	Part Status	Buy Online
MT29F128G08AUCBBH312:B	Production	Available

Please Note: Distributor inventory is an estimate and may not reflect actual available memory. Some links on this page will take you from the Micron web site. Micron does not control the content on these web sites.